## Energy Bands and Fermi Surfaces

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## From Bonds to Bands



Separation r

If a very large number of atoms are involved, as in the case of a real solid, then the energy levels will lie on a quasi- continuous scale and one therefore speaks of energy bands. The broadening of the band depends on the overlap of the wavefunctions concerned. Thus for the deep lying levels the broadening is small, and these "core levels" retain their atomic shell-like character even in the solid. For the highest occupied levels, on the other hand, the broadening is so large that the s -, p and where present, d-levels merge into a single band.

## Hydrogen Molecule

Consider two hydrogen atoms to form into a molecule, each with an electron in the $1 s$ ground state, their wavefunctions are $\psi_{A}$ and $\psi_{B}$, respectively.

As the atoms are brought together, their wavefunctions overlap. We consider the two combinations $\psi_{A} \pm \psi_{B}$. Each combination shares an electron with the two protons, but an electron in the state $\psi_{A}+\psi_{B}$ will have a somewhat lower energy than in the state $\psi_{A}-\psi_{B}$.

(a)

(b)

(c)

As free atoms are brought together, the coulomb interaction between the atom cores and the electron splits the energy levels, spreading them into bands. Each state of given quantum number of the free atom is spread in the crystal into a band of energies. The width of the band is proportional to the strength of the overlap interaction between neighboring atoms.
There will also be bands formed from $p, d, \ldots$ states $(I=1,2, \ldots)$ of the free atoms. States degenerate in the free atom will form different bands. Each will not have the same energy as any other band over any substantial range of the wavevector. Bands may coincide in energy at certain values of $\mathbf{k}$ in the Brillouin zone.

The 1 s band of a ring of 20 hydrogen atoms calculated by the tight-binding method


## Tight Binding Method

The tight binding approximation is also called the linear combination of atomic orbital (LCAO) approximation in which the one electron wavefunction $\psi_{\mathbf{k}}(\mathbf{r})$ is built from the electron wavefunction of an isolated atom, $\varphi(\mathbf{r})$.

$$
\psi_{\mathbf{k}}(\mathbf{r})=\sum_{j} C_{\mathbf{k} j} \varphi\left(\mathbf{r}-\mathbf{r}_{j}\right)
$$

where the sum is over all lattice points.
This function is of the Bloch form if $C_{\mathbf{k} j}=N^{-1 / 2} e^{i \mathbf{k} \cdot \mathbf{r}_{j}}$ for a crystal of $N$ atoms:

$$
\psi_{\mathbf{k}}(\mathbf{r})=N^{-1 / 2} \sum_{j} \exp \left(i \mathbf{k} \cdot \mathbf{r}_{j}\right) \varphi\left(\mathbf{r}-\mathbf{r}_{j}\right)
$$

We find the first-order energy by calculating the diagonal matrix elements of the hamiltonian of the crystal:

$$
\langle\mathbf{k}| H|\mathbf{k}\rangle=N^{-1} \sum_{j} \sum_{m} \exp \left[i \mathbf{k} \cdot\left(\mathbf{r}_{j}-\mathbf{r}_{m}\right)\right]\left\langle\varphi_{m}\right| H\left|\varphi_{j}\right\rangle,
$$

where $\varphi_{m} \equiv \varphi\left(\mathbf{r}-\mathbf{r}_{m}\right)$. Writing $\boldsymbol{\rho}_{m}=\mathbf{r}_{m}-\mathbf{r}_{j}$,

$$
\langle\mathbf{k}| H|\mathbf{k}\rangle=\sum_{m} \exp \left(-i \mathbf{k} \cdot \boldsymbol{\rho}_{m}\right) \int d V \varphi^{*}\left(\mathbf{r}-\boldsymbol{\rho}_{m}\right) H \varphi(\mathbf{r}) .
$$

We consider the integrals over the same atom and the nearest neighbor atoms only, then

$$
\int d V \varphi^{*}(\mathbf{r}) H \varphi(\mathbf{r})=-\alpha ; \quad \int d V \varphi^{*}(\mathbf{r}-\boldsymbol{\rho}) H \varphi(\mathbf{r})=-\gamma ;
$$

and we have the first-order energy, provided $\langle\mathbf{k} \mid \mathbf{k}\rangle=1$ :

$$
\langle\mathbf{k}| H|\mathbf{k}\rangle=-\alpha-\gamma \sum_{m} \exp \left(-i \mathbf{k} \cdot \boldsymbol{\rho}_{m}\right)=\epsilon_{\mathbf{k}} .
$$

For a simple cubic structure the nearest-neighbor atoms are at

$$
\boldsymbol{\rho}_{m}=( \pm a, 0,0) ; \quad(0, \pm a, 0) ; \quad(0,0, \pm a)
$$

we have

$$
\epsilon_{\mathrm{k}}=-\alpha-2 \gamma\left(\cos k_{x} a+\cos k_{y} a+\cos k_{x} a\right) .
$$

Thus the energies are confined to a band of width $12 \gamma$. The weaker the overlap, the narrower is the energy band.

If $k a \ll 1, \epsilon_{k} \simeq-\alpha-6 \gamma+\gamma k^{2} a^{2}$, the effective mass $m^{*}=\hbar^{2} / 2 \gamma a^{2}$
When the overlap integral $\gamma$ is small, the band is narrow and the effective mass is high.

For the bcc structure with eight nearest neighbors,

$$
\epsilon_{\mathbf{k}}=-\alpha-8 \gamma \cos \frac{1}{2} k_{x} a \cos \frac{1}{2} k_{y} a \cos \frac{1}{2} k_{z} a .
$$

For the fcc structure with twelve nearest neighbors,

$$
\epsilon_{\mathbf{k}}=-\alpha-4 \gamma\left(\cos \frac{1}{2} k_{y} a \cos \frac{1}{2} k_{z} a+\cos \frac{1}{2} k_{z} a \cos \frac{1}{2} k_{x} a+\cos \frac{1}{2} k_{x} a \cos \frac{1}{2} k_{y} a\right)
$$



A constant energy surface of an fcc crystal structure in the nearest neighbor tight-binding approximation. The surface shown has $\epsilon=-\alpha+2|\gamma|$.

The tight-binding (or LCAO) approximation is quite good for inner electrons of atoms, but it is not often good description for the conduction electrons. It is used to describe approximately the $d$ bands of transition metals and the valence bands of diamondlike and inert gas crystals.

## Wigner Seitz Method

A Bloch function satisfies the wave equation

$$
\left(\frac{1}{2 m} \mathbf{p}^{2}+U(\mathbf{r})\right) e^{i \mathbf{k} \mathbf{r}} u_{\mathbf{k}}(\mathbf{r})=\epsilon_{\mathbf{k}} e^{i \mathbf{k} \mathbf{r}} u_{\mathbf{k}}(\mathbf{r}) .
$$

With $\mathbf{P}=-i \hbar \boldsymbol{\nabla}$, we have

$$
\begin{gathered}
\mathbf{p} e^{i \mathbf{k} \cdot \mathbf{r}} u_{\mathbf{k}}(\mathbf{r})=\hbar \mathbf{k} e^{i \mathbf{k} \cdot \mathbf{r}} u_{\mathbf{k}}(\mathbf{r})+e^{i \mathbf{k} \mathbf{r}} \mathbf{p} u_{\mathbf{k}}(\mathbf{r}) ; \\
\mathbf{p}^{2} e^{i \mathbf{k} \mathbf{r}} u_{\mathbf{k}}(\mathbf{r})=(\hbar k)^{2} e^{i \mathbf{k} \mathbf{r}} u_{\mathbf{k}}(\mathbf{r})+e^{i \mathbf{k} \mathbf{r}}(2 \hbar \mathbf{k} \cdot \mathbf{p}) u_{\mathbf{k}}(\mathbf{r})+e^{i \mathbf{k} \cdot \mathbf{r}} \mathbf{p}^{2} u_{\mathbf{k}}(\mathbf{r}) ; \\
\text { So, } \quad\left(\frac{1}{2 m}(\mathbf{p}+\hbar \mathbf{k})^{2}+U(\mathbf{r})\right) u_{\mathbf{k}}(\mathbf{r})=\epsilon_{\mathbf{k}} u_{\mathbf{k}}(\mathbf{r}) .
\end{gathered}
$$

At $\mathbf{k}=0$ we have $\psi_{0}=u_{0}(\mathbf{r})$, where $u_{0}(\mathbf{r})$ has the periodicity of the lattice, sees the ion cores, and near them will look like the wavefunction of the free atom.

We then approximate the exact wavefunction $\psi_{\mathrm{k}}$ with $u_{0}(r)$,

$$
\begin{aligned}
& \text { for } \mathbf{k} \neq 0, \quad \psi_{\mathbf{k}}=\exp (i \mathbf{k} \cdot \mathbf{r}) u_{0}(r) \\
& \left(\frac{1}{2 m} \mathbf{p}^{2}+U(\mathbf{r})\right) u_{0}(\mathbf{r})=\epsilon_{0} u_{0}(\mathbf{r}), \quad \epsilon_{\mathbf{k}}=\epsilon_{0}+\left(\hbar^{2} k^{2} / 2 m\right) .
\end{aligned}
$$

In a spherical approximation to the shape of the smallest WignerSeitz cell we use the Wigner-Seitz boundary condition $(d \psi / d r) r_{0}=0$, where $r_{0}$ is the radius of a sphere equal in volume to a primitive cell of the lattice.



The stability of the simple metals with respect to free atoms is caused by the lowering of the energy of the Bloch orbital with $k=0$ in the crystal.

## Many-electron Hamiltonian

For a solid, the many-electron Hamiltonian whose Schrödinger wave equation must be solved is

$$
\begin{aligned}
\mathcal{H}= & -\frac{\hbar^{2}}{2 m} \sum_{i(\text { electrons) }} \nabla_{i}^{2}-\sum_{\substack{a(\text { (nucleei) } \\
i \text { (electrons) }}} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{a i}} \\
& +\frac{1}{2} \sum_{a, b(\text { nuclei) })}^{\prime} \frac{Z_{a} Z_{b} e^{2}}{4 \pi \varepsilon_{0} R_{a b}}+\frac{1}{2} \sum_{i, j \text { (electron) }}^{\prime} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{i j}}
\end{aligned}
$$



The many-electron Hamiltonian:

$$
\begin{aligned}
\mathscr{H}= & -\frac{\hbar^{2}}{2 m} \sum_{i(\text { electrons })} \nabla_{i}^{2}-\sum_{\substack{a(\text { nuclei) } \\
i(\text { electrons })}} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{a i}} \\
& +\frac{1}{2} \sum_{a, b \text { (nuclei) }}^{\prime} \frac{Z_{a} Z_{b} e^{2}}{4 \pi \varepsilon_{0} R_{a b}}+\frac{1}{2} \sum_{i, j \text { (electron) }}^{\prime} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{i j}} .
\end{aligned}
$$

1. The first term in the Hamiltonian is the operator representing the kinetic energy of all the electrons. Each different $i$ corresponds to a different electron.
2. The second term is the potential energy of interaction of all of the electrons with all of the nuclei, and $r_{a i}$ is the distance from the $a$ th nucleus of $Z_{a}$ to the ith electron.
3. The third term is the Coulomb potential energy of interaction between the nuclei. $R_{a b}$ is the distance between nucleus $a$ and nucleus $b$. The prime on the sum as usual means omission of those terms for which $a=b$.
4. The fourth term is the Coulomb potential energy of interaction between the electrons, and $r_{i j}$ is the distance between the $i$ th and $j$ th electrons.

$$
\begin{aligned}
\mathcal{H}= & -\frac{\hbar^{2}}{2 m} \sum_{i \text { (electrons) }} \nabla_{i}^{2}-\sum_{a \text { (nuclei) }}^{i \text { (electrons) }} \\
& \frac{e^{2}}{4 \pi \varepsilon_{0} r_{a i}} \\
& +\frac{1}{2} \sum_{a, b \text { (nugloi) }}^{\prime} \frac{Z_{a} R_{b} e^{2}}{4 \pi \varepsilon_{0} R_{a b}}+\frac{1}{2} \sum_{i, j \text { (electron) }}^{\prime} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{i j}} .
\end{aligned}
$$

This N -electron Hamiltonian is unnecessarily cumbersome. It is more convenient to write it with Born-Oppenheimer approximation,

$$
\begin{aligned}
& \mathcal{H}\left(x_{1} \cdots x_{n}\right)=\sum_{i=1}^{N} \mathcal{H}(i)+\frac{1}{2} \sum_{i, j}^{\prime} V(i j) \\
& \mathcal{H}(i)=\left(-\hbar^{2} / 2 m\right) \nabla_{i}^{2}-\sum_{\substack{a \text { (nuclei) } \\
i \text { (electrons) }}} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{a i}} \\
& V(i j)=V(j i)=\frac{1}{2} \sum_{i, j \text { (electron) }}^{\prime} \frac{e^{2}}{4 \pi \varepsilon_{0} r_{i j}}
\end{aligned}
$$

## Density Functional Theory

A $N$-electron state described by a wavefunction $\Psi\left(\mathbf{r}_{1}, \ldots, r_{N}\right)$ satisfies the many-electron time-independent Schrödinger equation

$$
\hat{H} \Psi=[\hat{T}+\hat{V}+\hat{U}] \Psi=\left[\sum_{i=1}^{N}\left(-\frac{\hbar^{2}}{2 m_{i}} \nabla_{i}^{2}\right)+\sum_{i=1}^{N} V\left(\mathbf{r}_{i}\right)+\sum_{i<j}^{N} U\left(\mathbf{r}_{i}, \mathbf{r}_{j}\right)\right] \Psi=E \Psi,
$$

The ground-state properties of a many-electron system are uniquely determined by an electron density that depends on only three spatial coordinates. Hohenberg and Kohn set down the groundwork for reducing the many-body problem of $N$ electrons with $3 N$ spatial coordinates to three spatial coordinates, through the use of functionals of the electron density $n(\mathbf{r})$, so that 1 ) the ground state wavefunction $\Psi_{0}$ is a unique functional of the ground state density $n_{0}(\mathbf{r})$;

$$
\begin{aligned}
n(\mathbf{r}) & =N \int \mathrm{~d}^{3} \mathbf{r}_{2} \cdots \int \mathrm{~d}^{3} \mathbf{r}_{N} \Psi^{*}\left(\mathbf{r}, \mathbf{r}_{2}, \ldots, \mathbf{r}_{N}\right) \Psi\left(\mathbf{r}, \mathbf{r}_{2}, \ldots, \mathbf{r}_{N}\right) \\
\Psi_{0} & =\Psi\left[n_{0}\right]
\end{aligned}
$$

and 2) the ground-state energy $E_{0}$ is a functional of $n_{0}$ :

$$
E_{0}=E\left[n_{0}\right]=\left\langle\Psi\left[n_{0}\right]\right| \hat{T}+\hat{V}+\hat{U}\left|\Psi\left[n_{0}\right]\right\rangle
$$

More generally, the contribution of the external potential $\langle\Psi| \hat{V}|\Psi\rangle$ can be written explicitly in terms of the density $n$ :

$$
V[n]=\int V(\mathbf{r}) n(\mathbf{r}) \mathrm{d}^{3} \mathbf{r}
$$

The effective single-particle potential can be written as

$$
V_{\mathrm{s}}(\mathbf{r})=V(\mathbf{r})+\int \frac{n\left(\mathbf{r}^{\prime}\right)}{\left|\mathbf{r}-\mathbf{r}^{\prime}\right|} \mathrm{d}^{3} \mathbf{r}^{\prime}+V_{\mathrm{XC}}[n(\mathbf{r})]
$$

where $V(\mathbf{r})$ is the external potential, the second term is the Hartree term describing the electron-electron Coulomb repulsion, and the last term $V_{\mathrm{xc}}$ is the exchange-correlation potential. Here, $V_{\mathrm{xc}}$ includes all the many-particle interactions.

Kohn-Sham equations of this auxiliary noninteracting system can be derived:

$$
\left[-\frac{\hbar^{2}}{2 m} \nabla^{2}+V_{\mathrm{S}}(\mathbf{r})\right] \varphi_{i}(\mathbf{r})=\varepsilon_{i} \varphi_{i}(\mathbf{r})
$$

which yields the orbitals $\varphi_{i}$ that reproduce the density $n(\mathbf{r})$ of the original many-body system

$$
n(\mathbf{r})=\sum_{i=1}^{N}\left|\varphi_{i}(\mathbf{r})\right|^{2}
$$

Usually one starts with an initial guess for $n(\mathbf{r})$, then calculates the corresponding $V_{s}$ and solves the Kohn-Sham equations for the $\varphi_{i}$. From these one calculates a new density and starts again. This procedure is then repeated until convergence is reached.

## Fermi Surfaces and Zone Schemes

The Fermi surface is the surface of constant energy $\epsilon_{F}$ in $\mathbf{k}$ space. The Fermi surface separates the unfilled orbitals from the filled orbitals, at absolute zero. The electrical properties of the metal are determined by the volume and shape of the Fermi surface, because the current is due to changes in the occupancy of states near the Fermi surface.


For any $\mathbf{k}^{\prime}$ outside of the first Brillouin zone, we can always find a reciprocal lattice vector $G$ so that $\mathbf{k}=\mathbf{k}^{\prime}+\mathbf{G}$ and $\mathbf{k}$ lies in the first Brillouin zone.

$$
\begin{aligned}
\psi_{\mathbf{k}^{\prime}}(\mathbf{r}) & =e^{i \mathbf{k}^{\prime} \cdot \mathbf{r}} u_{\mathbf{k}^{\prime}}(\mathbf{r})=e^{i \mathbf{k} \cdot \mathbf{r}}\left(e^{-i \mathbf{G} \cdot \mathbf{r}} u_{\mathbf{k}^{\prime}}(\mathbf{r})\right) \\
& =e^{i \mathbf{k} \cdot \mathbf{r}} u_{\mathbf{k}}(\mathbf{r})=\psi_{\mathbf{k}}(\mathbf{r})
\end{aligned}
$$

## Reduced, Extended and Periodic Zone Schemes


(a)
(b)
(c)

Figare 4 Three energy bands of a linear lattice plotted in (a) the extended (Brillowin), (b) reduced, and (c) periodic zone schemes

## Brillouin Zones of Square Lattice

For a simple square lattice of atoms with interatomic distance a. Its reciprocal lattice will also be square, with reciprocal lattice base vector of length $2 \pi / a$.



2nd zone


3ed zone

## Construction of Fermi Surfaces for Free Electrons



Brillouin zones of a square lattice in two dimensions. The circle shown is a surface of constant energy for free electrons; it will be the Fermi surface for some particular value of the electron concentra- tion. The total area of the filled region in $\mathbf{k}$ space depends only on the electron concentration and is inde- pendent of the interaction of the electrons with the lattice. The shape of the Fermi surface depends on the lattice interaction, and the shape will not be an exact circle in an actual lattice.


1st zone


2nd zone


3rd zone

Fermi circle viewed in the reduced zone scheme

## Nearly Free Electrons Fermi Surfaces

From free electrons Fermi surfaces to nearly free electrons Fermi surfaces:

- The interaction of the electron with the periodic potential of the crystal creates energy gaps at the zone boundaries.
- Almost always the Fermi surface will intersect zone boundaries perpendicularly.
- The crystal potential will round out sharp corners in the Fermi surfaces.
- The total volume enclosed by the Fermi surface depends only on the electron concentration and is independent of the details of the lattice interaction.


2nd zone


3rd zone


Free electron Fermi circle in the third zone drawn in the periodic zone scheme

## Three Types of Orbits in Magnetic Field

Lorentz force on the electron:

$$
\hbar \frac{d \mathbf{k}}{d t}=-\frac{e}{c} \mathbf{v} \times \mathbf{B} ; \quad \rightarrow \quad \frac{d \mathbf{k}}{d t}=-\frac{e}{\hbar^{2} c} \nabla_{\mathbf{k}} \epsilon \times \mathbf{B} ; \quad \mathbf{v}=\hbar^{-1} \nabla_{\mathbf{k}} \epsilon
$$



Motion in a magnetic field of the wavevector of an electron on the Fermi surface
Orbits that enclose filled states are electron orbits. Orbits that enclose empty states are hole orbits. Orbits that move from zone to zone without closing are open orbits.

## Schematic Shape of a 3-D Fermi Surface

In 3D crystals the periodic potential distorts the shape of a Fermi sphere in the vicinity of the BZ boundary. A schematic example for a simple cubic lattice and a crude model $\mathrm{E}(\mathrm{k})$ function is shown here:

(a)

(b)

Constant energy surface in the Brillouin zone of a simple cubic lattice, for the assumed energy band $\epsilon_{\mathbf{k}}=-\alpha-2 \gamma\left(\cos k_{x} a+\cos k_{y} a+\cos k_{z} a\right)$.

Note: the Fermi circle does not completely fill the $1^{\text {st }} \mathrm{BZ}$ but makes contact with the $1^{\text {st }} \mathrm{BZ}$ boundary along the [100] directions.

## Shape of 3-D Energy Bands in a Real Metal

In 3D the energy bands are plotted along the major symmetry directions in the $1^{\text {st }}$ BZ. Many of the high symmetry points on the $1^{\text {st }} \mathrm{BZ}$ boundary are labeled by letters.

The gamma point ( $\Gamma$ ) is always the zone center, where $\mathrm{k}=0$.

(a)



Figure 7.20 A comparison of the empty-lattice energy bands (a) and detailed calculations for Al (b). Again the nearly free electron character of Al is confirmed. (Harrison, W., Pseudopotentials in the Theory of Metals, 1966, Addison-Wesley Publishing Co., Reading, Massachusetts. Figures 3.19 and 3.20. Reprinted with permission.)

## Quantization of Orbits in Magnetic Field

The momentum $\mathbf{p}$ of a particle (with charge $q$ ) in a magnetic field $\mathbf{B}$ is the sum of two parts:

$$
\mathbf{p}=\mathbf{p}_{\text {kin }}+\mathbf{p}_{\text {field }}=\hbar \mathbf{k}+q \mathbf{A} / c \text { and } \quad \mathbf{B}=\boldsymbol{\nabla} \times \mathbf{A}
$$

The orbits in a magnetic field are quantized by the Bohr-Sommerfeld relation

$$
\oint \mathbf{p} \cdot d \mathbf{r}=(n+\gamma) 2 \pi h,
$$

when $n$ is an integer and $\gamma$ is a phase correction that for free electrons has the value $1 / 2$. The equation of motion of a particle of charge $q$ in a magnetic field is

$$
\hbar \frac{d \mathbf{k}}{d t}=\frac{q}{c} \frac{d \mathbf{r}}{d t} \times \mathbf{B} \quad \Longrightarrow \quad \hbar \mathbf{k}=\frac{q}{c} \mathbf{r} \times \mathbf{B}
$$

Thus,

$$
\begin{aligned}
\oint_{\mathbf{p}} \cdot d \mathbf{r} & =\oint \hbar \mathbf{k} \cdot d \mathbf{r}+\frac{q}{c} \oint \mathbf{A} \cdot d \mathbf{r} \\
& =\frac{q}{c} \oint \mathbf{r} \times \mathbf{B} \cdot d \mathbf{r}+\frac{q}{c} \int \operatorname{curl} \mathbf{A} \cdot d \boldsymbol{\sigma} \\
& =-\frac{q}{c} \mathbf{B} \cdot \oint \mathbf{r} \times d \mathbf{r}+\frac{q}{c} \int \mathbf{B} \cdot d \boldsymbol{\sigma} \\
& =-\frac{2 q}{c} \Phi+\frac{q}{c} \Phi=-\frac{q}{c} \mathbf{\Phi}=(n+\gamma) 2 \pi \hbar
\end{aligned}
$$

It follows that the orbit of an electron is quantized in such a way that the flux through it is

$$
\Phi_{n}=(n+\gamma)(2 \pi \hbar c / e)
$$

The flux unit $2 \pi \hbar c / e=4.14 \times 10^{-7}$ gauss $\mathrm{cm}^{2}$ or $\mathrm{T} \mathrm{m}^{2}$.
$\because \quad \hbar \mathbf{k}=\frac{q}{c} \mathbf{r} \times \mathbf{B}$, a line element $\Delta r$ in the plane normal to $\mathbf{B}$ is related to $\Delta k$ by $\Delta r=(\hbar c / e B) \Delta k$, so that the area $S_{n}$ in $\mathbf{k}$ space is related to the area $A_{n}$ of the orbit in $r$ space by

$$
A_{n}=(\hbar c / e B)^{2} S_{n}
$$

Thus,

$$
\begin{aligned}
\Phi_{n} & =B A_{n}=\left(\frac{\hbar c}{e}\right)^{2} \frac{1}{B} S_{n}=(n+\gamma) \frac{2 \pi \hbar c}{e} \\
& \Longrightarrow S_{n}=(n+\gamma) \frac{2 \pi e}{\hbar c} B
\end{aligned}
$$

## De Haas-van Alphen Effect

The de Haas-van Alphen effect is the oscillation of the magnetic moment of a metal as a function of the static magnetic field intensity. The effect can be observed in pure specimens at low temperatures in strong magnetic fields.
Assume the magnetic field is applied along the $z$ axis, the area of an orbit in $k_{x}, k_{y}$ plane is quantized and the area between successive orbits is

$$
\Delta S=S_{n}-S_{n-1}=2 \pi e B / \hbar c
$$


(a)
(b)

(d)

Explanation of the de Haas-van Alphen effect for a free electron gas in two dimensions in a magnetic field with $B_{1}<B_{2}<B_{3}$.

## Degeneracy of Orbits in Magnetic Field


(a)

(b)
allowed electron orbitals in two dimensions
The area between successive circles is

$$
\pi \Delta\left(k^{2}\right)=2 \pi k(\Delta k)=\left(2 \pi m / \hbar^{2}\right) \Delta \epsilon=2 \pi m \omega_{c} / \hbar-2 \pi e B / \hbar c
$$

The number of free electron orbits collapsed into a Landau level is

$$
D=(2 \pi e B / \hbar c)(L / 2 \pi)^{2}=\rho B, \quad \text { and } \quad \rho=e L^{2} / 2 \pi \hbar c
$$

## Orbital Degeneracy Increases with B



Figure 25 (a) The heavy line gives the number of particles in levels which are completely occupied in a magnetic field $B$, for a two-dimensional system with $N=50$ and $\rho=0.50$. The shaded area gives the number of particles in levels partially occupied. The value of $s$ denotes the quantum number of the highest level which is completely filled. Thus at $B=40$ we have $s=2$; the levels $n=1$ and $n=2$ are filled and there are 10 particles in the level $n=3$. At $B=50$ the level $n=3$ is empty. (b) The periodicity in $1 / B$ is evident when the same points are plotted against $1 / B$.

## dHvA Oscillation

The magnetic moment $\mu$ of a system at absolute zero is given by $\mu=$ $-\partial U / \partial B$. The moment here is an oscillatory function of $1 / B$. This oscillatory magnetic moment of the Fermi gas at low temperatures is the de Haas-van Alphen effect.


The oscillations occur at equal interval of $1 / B$ so that

$$
\Delta\left(\frac{1}{B}\right)=\frac{2 \pi e}{\hbar c S}
$$

where $S$ is the extremal area of the Fermi surface normal to the direction of $\boldsymbol{B}$.

## Extremal Orbits in Magnetic Field

For a Fermi surface of general shape the sections at different values of $k B$ will have different periods. Here $k B$ is the component of $k$ along the direction of the magnetic field. The response will be the sum of contributions from all sections or all orbits. But the dominant response of the system comes from orbits whose periods are stationary with respect to small changes in $\mathbf{K B}$. Such orbits are called extremal orbits. Thus, in the figure, the section $A A^{\prime}$ dominates the observed cyclotron period.


The orbits in the section $A A^{\prime}$ are extremal orbits: the cyclotron period is roughly constant over a reasonable section of the Fermi surface. Other sections such as $B B^{\prime}$ have orbits that vary in period along the section.

## Fermi Surface of Copper

Even if the free-electron Fermi sphere does not intersect a BZ boundary, its shape can still be affected at points close to the boundary where the energy bands begin to deviate from the free-electron parabolic shape. This is the case with Cu .


Figure 7.25 The complete band structure diagram for Cu along the major symmetry directions (compare with the Brillouin zone of Fig. 7.15b). The diagram to the right is a simple schematic representation of the integrated density of levels and is convenient as a basis for the discussion of many physical properties of the later 'd' metals. We shall soon find that the sp valence electrons are responsible for the electrical conductivity of these metals; one therefore speaks of the


Fermi surface of copper 'conduction band'. (After Segall 1962.)

## Fermi Surface of Gold



Dog's bone orbit of an electron on the Fermi surface of copper or gold in a magnetic field.


De Haas-van Alphen effect in gold with B |/ [110]. The oscillation is from the dog's bone orbit of the left figure.

## Photoemission Process

$$
\begin{aligned}
I_{\mathrm{ph}}\left(\boldsymbol{k}_{\|}^{(\mathrm{el})}, E_{\mathrm{kin}}\right) & \left.\propto \sum_{i, j} \sum_{k_{z}}\left|\left\langle j, \boldsymbol{k}_{\|}, k_{z}\right| \boldsymbol{x}\right| i, \boldsymbol{k}_{\|}, k_{z}\right\rangle\left.\right|^{2} \\
& \times \delta\left(E_{\mathrm{kin}}+E_{\mathrm{vac}}-E^{(\mathrm{i})}\left(\boldsymbol{k}_{\|}, k_{z}\right)-h \nu\right) \delta\left(\boldsymbol{k}_{\|}-\boldsymbol{k}_{\|}^{(\mathrm{el})}\right)
\end{aligned}
$$

(a)

(b)


$$
E_{\mathrm{kin}}=-E_{\mathrm{vac}}+E^{(\mathrm{i})}\left(\boldsymbol{k}_{\|}, k_{z}\right)+h \nu
$$

Here, i, j denote the initial and final bands, $\boldsymbol{k}_{| |}, k_{z}$ are the components of the wave vector in the initial and the final state, and $E^{(i)}$, $E_{\text {vac }}$ are the energies of the initial state and the vacuum level.

## Photoemission Spectra of $\mathrm{Cu}(111)$ and $\mathrm{Cu}(110)$



Photoemission spectra of $\mathrm{Cu}(111)$ and $\mathrm{Cu}(110)$ surfaces serving to establish the wave vector $k_{111}$ for bulk electronic states: the two prominent peaks appearing in the spectra along [111] on $\mathrm{Cu}(111)$ are found at an angle of $\theta=52.5^{\circ}$ in the [110] zone on $\mathrm{Cu}(110)$. The magnitude of $k_{111}$ is determined by considering $\boldsymbol{k}_{\text {|| }}$ conservation.
$k_{\|}^{(\text {int })}=k_{\|}^{(\text {ext })} \Rightarrow k_{111}^{(\text {(int })} \sin 35^{\circ}=k^{(\text {ext })} \sin 52.5^{\circ}$

## Angle-Resolved PhotoEmission Spectroscopy (ARPES)



$$
E_{b}=E-h v+W
$$

$$
k_{\|}^{i}=k_{\|}^{f}=\sqrt{2 m E / \hbar^{2}} \sin \theta
$$

$$
k_{1}^{i}=k^{\dagger}-G=\sqrt{2 m E / \hbar^{2}} \cos \theta-G
$$





## Concentric Hemispherical Analyzer (CHA)



$$
\Delta \mathrm{E} / \mathrm{E}_{0}=\mathrm{s} / \mathrm{R}_{0}
$$

s : mean slit width; $\mathrm{R}_{0}$ : mean radius

Hemispherical Electron Analyser


## Problems

1. Brillouin zones of two-dimensional divalent metal. A two-dimensional metal in the form of a square lattice has two conduction electrons per atom. In the al- most free electron approximation, sketch carefully the electron and hole energy surfaces. For the electrons choose a zone scheme such that the Fermi surface is shown as closed.
2. De Haas-van Alphen period of potassium. (a) Calculate the period $\Delta(1 / B)$ expected for potassium on the free electron model. (b) What is the area in real space of the extremal orbit, for $B=10 \mathrm{kG}=1 \mathrm{~T}$ ? The same period applies to oscillations in the electrical resistivity, known as the Shubnikov-de Haas effect.

## Problems

3. Landau levels. The vector potential of a uniform magnetic field $B z^{\wedge}$ is A = -Byx^^ in the Landau gauge. The hamiltonian of a free electron without spin is

$$
H=-\left(\hbar^{2} / 2 m\right)\left(\partial^{2} / \partial y^{2}+\partial^{2} / \partial z^{2}\right)+(1 / 2 m)[-i \hbar \partial / \partial x-e y B / c]^{2} .
$$

We will look for an eigenfunction of the wave equation $H \psi=\epsilon \psi$ in the form

$$
\psi=\chi(y) \exp \left[i\left(k_{x} x+k_{z} z\right)\right] .
$$

(a) Show that $\chi(y)$ satisfies the equation

$$
\left(\hbar^{2} / 2 m\right) d^{2} \chi / d y^{2}+\left[\epsilon-\left(\hbar^{2} k_{z}^{2} / 2 m\right)-\frac{1}{2} m \omega_{c}^{2}\left(y-y_{0}\right)^{2}\right] \chi=0,
$$

where $\omega_{c}=e B / m c$ and $y_{0}=c \hbar k_{x} / e B$.
(b) Show that this is the wave equation of a harmonic oscillator with frequency $\omega_{c}$, where

$$
\epsilon_{n}=\left(n+\frac{1}{2}\right) \hbar \omega_{c}+\hbar^{2} k_{z}^{2} / 2 m .
$$

